#### DESCRIPTION

The SPN4402 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application, notebook computer power management and other battery powered circuits where high-side switching.

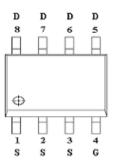
#### FEATURES

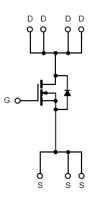
- $30V/12A,RDS(ON) = 13m\Omega@VGS = 10V$
- $30V/10A,RDS(ON) = 18m\Omega@VGS = 4.5V$
- Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ◆ SOP 8P package design

#### APPLICATIONS

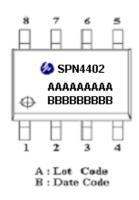
- Power Management in Note book
- Battery Powered System
- DC/DC Converter
- Load Switch
- LCD Display inverter

#### PIN CONFIGURATION(SOP - 8P)





#### PART MARKING





PIN DESCRIPTION						
Pin	Symbol	Description				
1	S	Source				
2	S	Source				
3	S	Source				
4	G	Gate				
5	D	Drain				
6	D	Drain				
7	D	Drain				
8	D	Drain				

#### **ORDERING INFORMATION**

Part Number	Package	Part Marking
SPN4402S8RGB	SOP- 8P	SPN4402

\* SPN4402S8RGB : 13" Tape Reel ; Pb – Free ; Halogen – Free

#### ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter	Symbol	Typical	Unit		
Drain-Source Voltage		VDSS	30	V	
Gate –Source Voltage		VGSS	±20	V	
	TA=25°C	I.	12		
Continuous Drain Current(TJ=150℃)	Та=70°С	ID	10	A	
Pulsed Drain Current	Ідм	30	А		
Continuous Source Current(Diode Conduction)		Is	2.3	А	
Demon Dissingtion	TA=25°C	Dr	2.5	W	
Power Dissipation	TA=70°C	PD	1.6	W	
Operating Junction Temperature		τJ	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		Røja	80	°C/W	

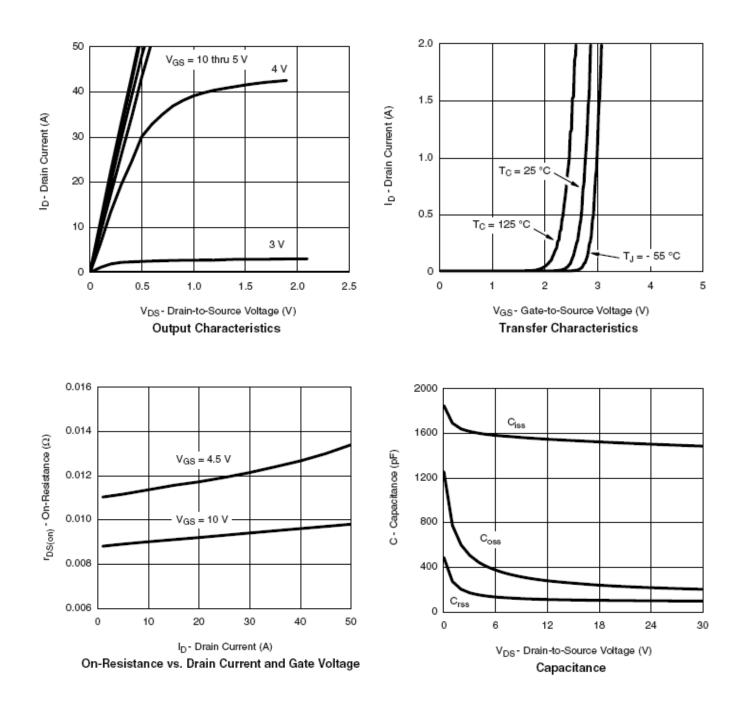


#### ELECTRICAL CHARACTERISTICS

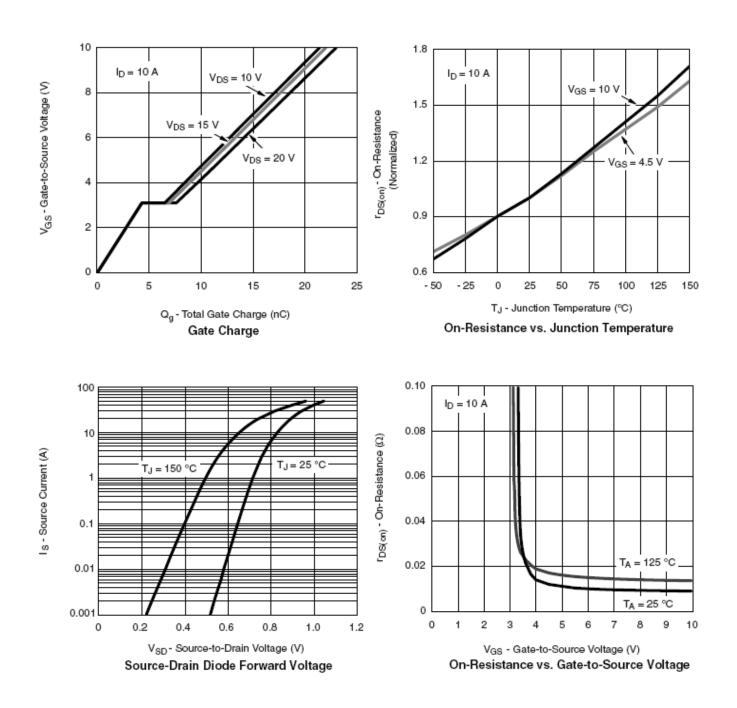
(TA=25°C Unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static			L.				
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	30			V	
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	1.0		3.0	v	
Gate Leakage Current	IGSS	VDS=0V,VGS=±20V			±100	nA	
		VDS=24V,VGS=0V			1	uA	
Zero Gate Voltage Drain Current	Idss	VDS=24V,VGS=0V TJ=55°C			5		
On-State Drain Current	ID(on)	VDS≥5V,VGS =10V	25			Α	
Drain-Source On-Resistance	RDS(on)	VGs= 10V,ID=12A		0.010	0.013	Ω	
Dram-Source On-Resistance	KDS(0n)	VGS=4.5V,ID=10A		0.013	0.018		
Forward Transconductance	gfs	VDS=15V,ID=6.2A		13		S	
Diode Forward Voltage	Vsd	Is=2.3A,VGs =0V		0.5	1.0	V	
Dynamic							
Total Gate Charge	Qg			10	18	nC	
Gate-Source Charge	Qgs	$V_{DS}=15V, V_{GS}=10V$ $I_{D}=2A$		2.8			
Gate-Drain Charge	Qgd			2.0			
Input Capacitance	Ciss			850		pF	
Output Capacitance	Coss	VDS=15VGS=0V f=1MHz		158			
Reverse Transfer Capacitance	Crss			120			
T O T	td(on)			10	15	nS	
Turn-On Time	tr	$V_{DD}=15V,RL=15\Omega$		4	12		
Term ORTime	td(off)	ID=5.0A,VGEN=10V RG=1 $\Omega$		15	30		
Turn-Off Time	tſ	]		10	15		

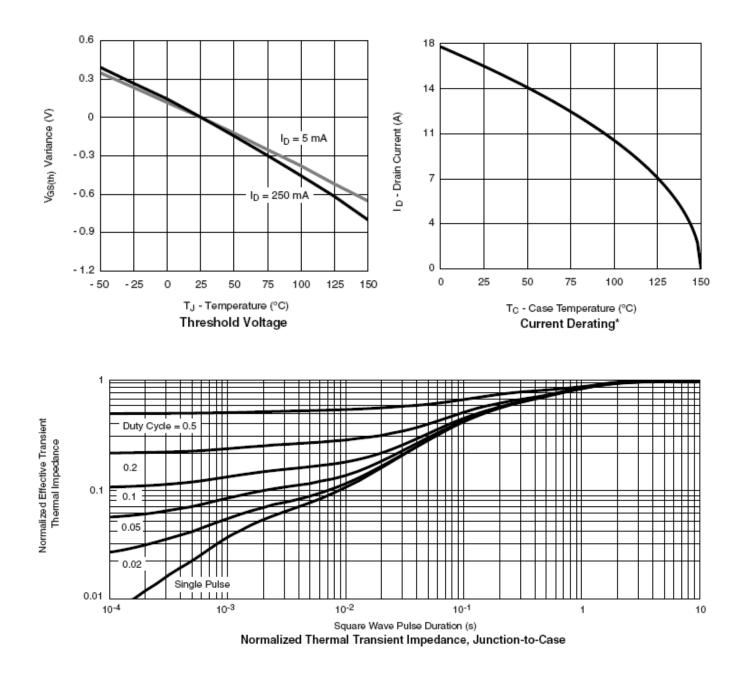
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

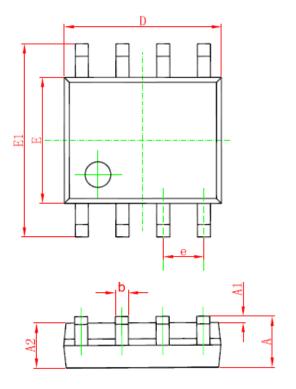


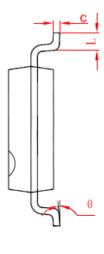
#### TYPICAL CHARACTERISTICS





#### SOP- 8 PACKAGE OUTLINE





0	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1.350	1. 750	0.053	0.069	
A1	0. 100	0. 250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0. 330	0. 510	0.013	0.020	
с	0. 170	0. 250	0.006	0.010	
D	4. 700	5. 100	0.185	0.200	
E	3.800	4.000	0.150	0. 157	
E1	5.800	6. 200	0. 228	0. 244	
е	1. 270 (BSC)		0.050 (BSC)		
L	0. 400	1. 270	0.016	0.050	
θ	0°	8°	0°	8°	



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